

October 1987 Revised March 2002

CD40106BC Hex Schmitt Trigger

General Description

The CD40106BC Hex Schmitt Trigger is a monolithic complementary MOS (CMOS) integrated circuit constructed with N and P-channel enhancement transistors. The positive and negative-going threshold voltages, V_{T+} and V_{T-} , show low variation with respect to temperature (typ 0.0005V/°C at $V_{DD}=10V),$ and hysteresis, $V_{T+}-V_{T-}\geq 0.2$ V_{DD} is guaranteed.

All inputs are protected from damage due to static discharge by diode clamps to V_{DD} and V_{SS} .

Features

- Wide supply voltage range: 3V to 15V
- High noise immunity: 0.7 V_{DD} (typ.)
- Low power TTL compatibility:

Fan out of 2 driving 74L or 1 driving 74LS

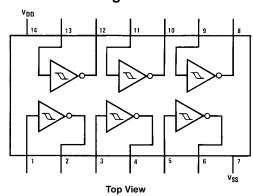
- \blacksquare Hysteresis: 0.4 V_{DD} (typ.),
 - 0.2 V_{DD} guaranteed
- Equivalent to MM74C14
- Equivalent to MC14584B

Ordering Code:

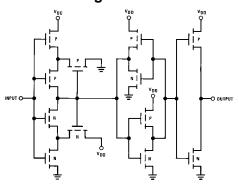
Order Number	Package Number	Package Description
CD40106BCM	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD40106BCN	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Connection Diagram



Schematic Diagram



Absolute Maximum Ratings(Note 1)

(Note 2)

-0.5 to +18 V_{DC}

 $\begin{array}{ll} \mbox{Input Voltage (V_{IN})} & -0.5 \mbox{ to V}_{DD} + 0.5 \mbox{ V}_{DC} \\ \mbox{Storage Temperature Range (T_S)} & -65^{\circ}\mbox{C to } +150^{\circ}\mbox{C} \end{array}$

Power Dissipation (P_D)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T_L)

DC Supply Voltage (V_{DD})

(Soldering, 10 seconds) 260°C

Recommended Operating Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3 to 15 V_{DC} Input Voltage (V_{IN}) 0 to V_{DD} V_{DC}

Operating Temperature Range (T_A) $-55^{\circ}C$ to $+125^{\circ}C$

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

DC Electrical Characteristics (Note 3)

Symbol	Parameter	Conditions	-5	–55°C		+25°C			+125°C	
	rarameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	$V_{DD} = 5V$		1.0			1.0		30	
		V _{DD} = 10V		2.0			2.0		60	μΑ
		$V_{DD} = 15V$		4.0			4.0		120	
V _{OL}	LOW Level Output	I _O < 1 μA								
	Voltage	$V_{DD} = 5V$		0.05			0.05		0.05	V
		$V_{DD} = 10V$		0.05			0.05		0.05	V
		$V_{DD} = 15V$		0.05			0.05		0.05	
OII	HIGH Level Output	I _O < 1 μA								
	Voltage	$V_{DD} = 5V$	4.95		4.95	5		4.95		V
		$V_{DD} = 10V$	9.95		9.95	10		0.95		V
		$V_{DD} = 15V$	14.95		14.95	15		14.95		
V_{T-}	Negative-Going Threshold	$V_{DD} = 5V, V_{O} = 4.5V$	0.7	2.0	0.7	1.4	2.0	0.7	2.0	
	Voltage	$V_{DD} = 10V, V_{O} = 9V$	1.4	4.0	1.4	3.2	4.0	1.4	4.0	V
		$V_{DD} = 15V, V_{O} = 13.5V$	2.1	6.0	2.1	5.0	6.0	2.1	6.0	
	Positive-Going Threshold	$V_{DD} = 5V, V_{O} = 0.5V$	3.0	4.3	3.0	3.6	4.3	3.0	4.3	
	Voltage	$V_{DD} = 10V, V_{O} = 1V$	6.0	8.6	6.0	6.8	8.6	6.0	8.6	V
		$V_{DD} = 15V, V_{O} = 1.5V$	9.0	12.9	9.0	10.0	12.9	9.0	12.9	
	Hysteresis (V _{T+} – V _{T-})	$V_{DD} = 5V$	1.0	3.6	1.0	2.2	3.6	1.0	3.6	
	Voltage	$V_{DD} = 10V$	2.0	7.2	2.0	3.6	7.2	2.0	7.2	V
		$V_{DD} = 15V$	3.0	10.8	3.0	5.0	10.8	3.0	10.8	
I _{OL}	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4		
ГОН	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		-0.51	-0.88		-0.36		
	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA
		$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4		
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10 ⁻⁵	-0.1		-1.0	μА
		$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 ⁻⁵	0.1		1.0	μΑ

Note 3: I_{OH} and I_{OL} are tested one output at a time.

AC Electrical Characteristics (Note 4)

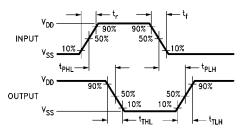
 $T_A = 25^{\circ}C$, $C_L = 50$ pF, $R_L = 200$ k, t_r and $t_f = 20$ ns, unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{PHL} or t _{PLH}	Propagation Delay Time from	V _{DD} = 5V		220	400	
	Input to Output	$V_{DD} = 10V$		80	200	ns
		$V_{DD} = 15V$		70	160	
t _{THL} or t _{TLH}	Transition Time	V _{DD} = 5V		100	200	
		$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	
C _{IN}	Average Input Capacitance	Any Input		5	7.5	pF
C _{PD}	Power Dissipation Capacity	Any Gate (Note 5)		14		pF

Note 4: AC Parameters are guaranteed by DC correlated testing.

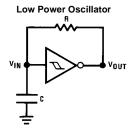
Note 5: C_{PD} determines the no load ac power consumption of any CMOS device. For complete explanation see 74C Family Characteristics Application Note,

Switching Time Waveforms



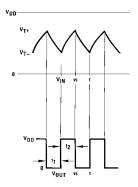
 $t_r = t_f = 20 \text{ ns}$

Typical Applications

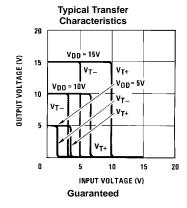


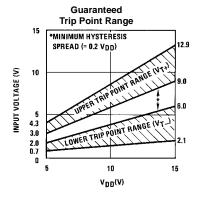
$$\begin{split} t_1 &\approx \text{RC } \ell \text{ n } \frac{V_{T+}}{V_{T-}} \\ t_2 &\approx \text{RC } \ell \text{ n } \frac{V_{DD} - V_{T-}}{V_{DD} - V_{T+}} \\ f &\approx \frac{1}{\text{RC } \ell \text{ n } \frac{V_{T-} \left(V_{DD} - V_{T-}\right)}{V_{T-} \left(V_{DD} - V_{T+}\right)} \end{split}$$

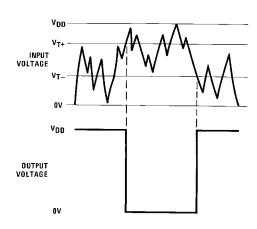
Note: The equations assume $t_1 + t_2 >> t_{PHL} + t_{PLH}$

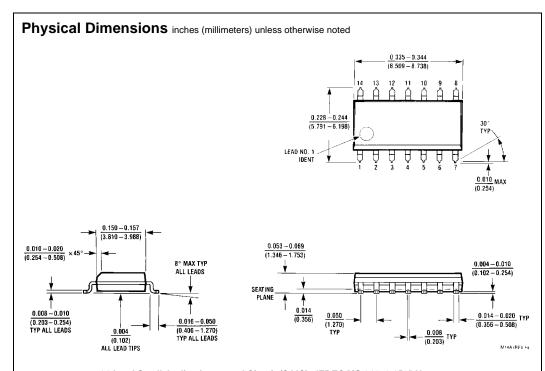


Typical Performance Characteristics



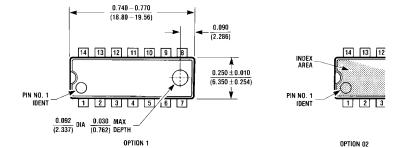


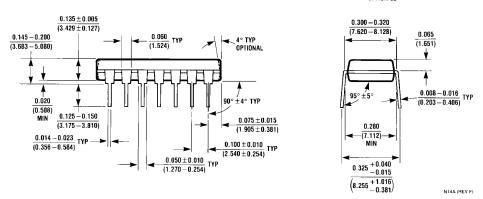




14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow Package Number M14A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)





14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide Package Number N14A

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